

## DATA SHEET

**NEC****MOS FIELD EFFECT TRANSISTOR****2SK4070****SWITCHING  
N-CHANNEL POWER MOS FET****DESCRIPTION**

The 2SK4070 is N-channel MOS FET device that features a low gate charge and excellent switching characteristics, and designed for high voltage applications such as switching power supply, AC adapter.

**FEATURES**

- Low on-state resistance  
 $R_{DS(on)} = 11 \Omega$  MAX. ( $V_{GS} = 10$  V,  $I_D = 0.5$  A)
- Low gate charge  
 $Q_G = 5$  nC TYP. ( $V_{DD} = 450$  V,  $V_{GS} = 10$  V,  $I_D = 1.0$  A)
- Gate voltage rating :  $\pm 30$  V
- Avalanche capability ratings

**<R> ORDERING INFORMATION**

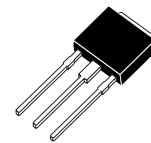
PART NUMBER	LEAD PLATING	PACKING	PACKAGE
2SK4070-S15-AY <sup>Note</sup>	Pure Sn (Tin)	Tube 70 p/tube	TO-251 (MP-3-a) typ. 0.39 g
2SK4070(1)-S27-AY <sup>Note</sup>		Tube 75 p/tube	TO-251 (MP-3-b) typ. 0.34 g
2SK4070-ZK-E1-AY <sup>Note</sup>		Tape 2500 p/reel	TO-252 (MP-3ZK) typ. 0.27 g
2SK4070-ZK-E2-AY <sup>Note</sup>			

**Note** Pb-free (This product does not contain Pb in external electrode.)

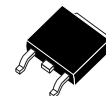
**ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ )**

Drain to Source Voltage ( $V_{GS} = 0$ V)	$V_{DSS}$	600	V
Gate to Source Voltage ( $V_{DS} = 0$ V)	$V_{GSS}$	$\pm 30$	V
Drain Current (DC) ( $T_C = 25^\circ\text{C}$ )	$I_{D(DC)}$	$\pm 1.0$	A
Drain Current (pulse) <sup>Note1</sup>	$I_{D(pulse)}$	$\pm 4.0$	A
Total Power Dissipation ( $T_C = 25^\circ\text{C}$ )	$P_{T1}$	22	W
Total Power Dissipation ( $T_A = 25^\circ\text{C}$ ) <sup>Note2</sup>	$P_{T2}$	1.0	W
Channel Temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$
Single Avalanche Current <sup>Note3</sup>	$I_{AS}$	0.8	A
Single Avalanche Energy <sup>Note3</sup>	$E_{AS}$	38.4	mJ

(TO-251)



(TO-252)



**Notes** 1.  $PW \leq 10 \mu\text{s}$ , Duty Cycle  $\leq 1\%$

2. Mounted on glass epoxy board of 40 mm  $\times$  40 mm  $\times$  1.6 mm

3. Starting  $T_{ch} = 25^\circ\text{C}$ ,  $V_{DD} = 150$  V,  $R_G = 25 \Omega$ ,  $V_{GS} = 20 \rightarrow 0$  V

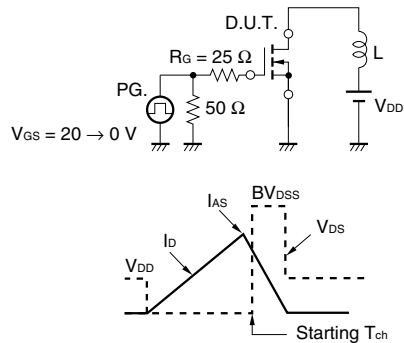
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**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)**

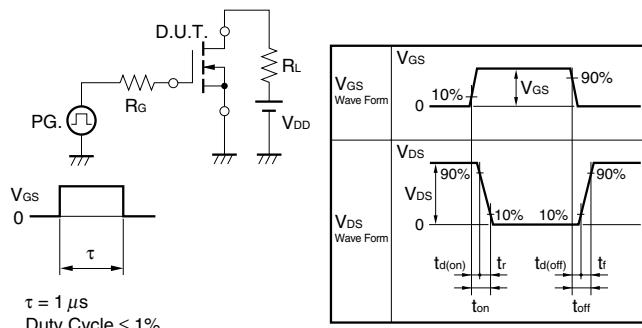
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 600 V, V <sub>GS</sub> = 0 V			100	μA
Gate Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±30 V, V <sub>DS</sub> = 0 V			±100	nA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	2.5	2.9	3.5	V
Forward Transfer Admittance <sup>Note</sup>	y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.5 A	0.2	0.4		S
Drain to Source On-state Resistance <sup>Note</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 0.5 A		9.2	11	Ω
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V,		110		pF
Output Capacitance	C <sub>oss</sub>	f = 1 MHz		50		pF
Reverse Transfer Capacitance	C <sub>rss</sub>			11		pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 150 V, I <sub>D</sub> = 0.5 A,		7.5		ns
Rise Time	t <sub>r</sub>	V <sub>GS</sub> = 10 V,		6		ns
Turn-off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> = 10 Ω		11		ns
Fall Time	t <sub>f</sub>			18		ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DD</sub> = 450 V,		5		nC
Gate to Source Charge	Q <sub>GS</sub>	V <sub>GS</sub> = 10 V,		1		nC
Gate to Drain Charge	Q <sub>GD</sub>	I <sub>D</sub> = 1.0 A		2.8		nC
Body Diode Forward Voltage <sup>Note</sup>	V <sub>F(S-D)</sub>	I <sub>F</sub> = 1.0 A, V <sub>GS</sub> = 0 V		0.86	1.5	V
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 1.0 A, V <sub>GS</sub> = 0 V,		135		ns
Reverse Recovery Charge	Q <sub>rr</sub>	di/dt = 100 A/μs		285		nC

**Note** Pulsed

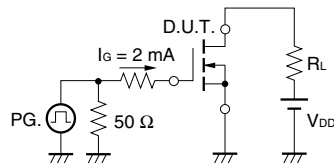
**TEST CIRCUIT 1 AVALANCHE CAPABILITY**



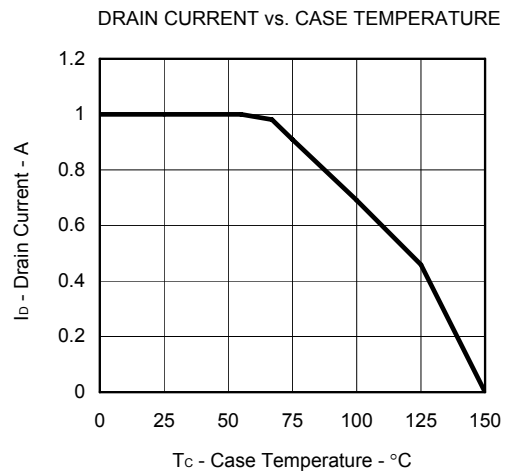
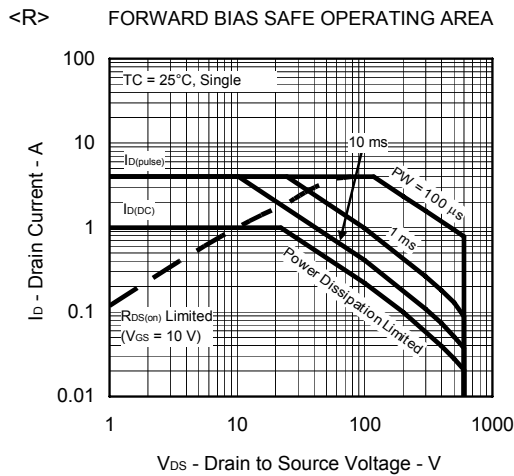
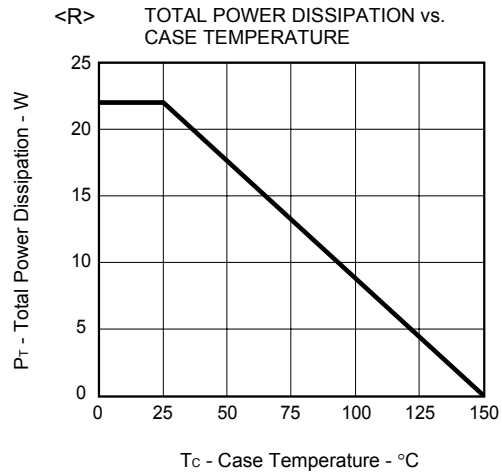
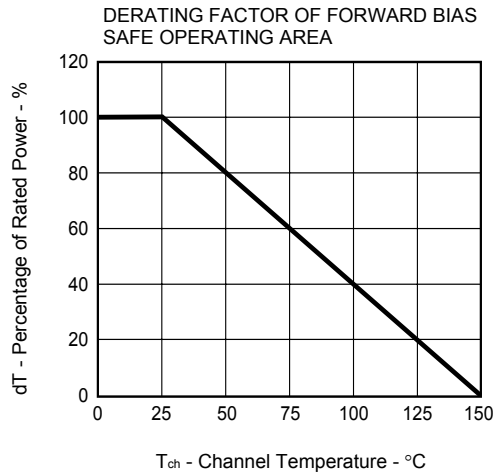
**TEST CIRCUIT 2 SWITCHING TIME**



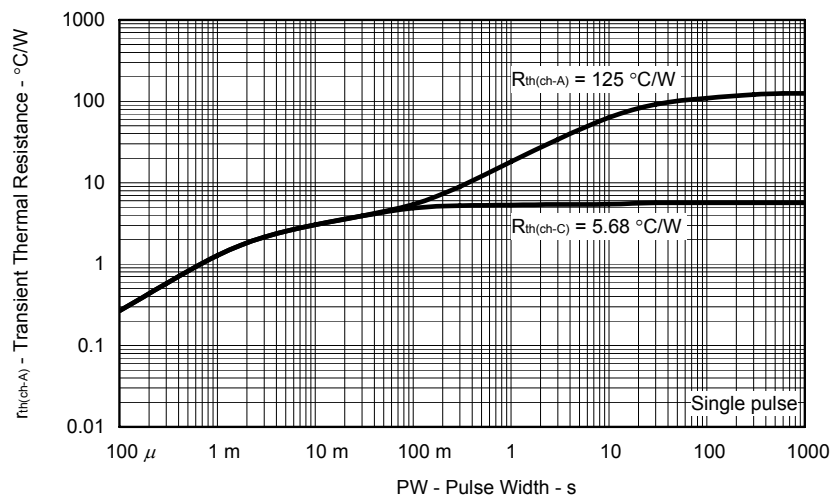
**TEST CIRCUIT 3 GATE CHARGE**



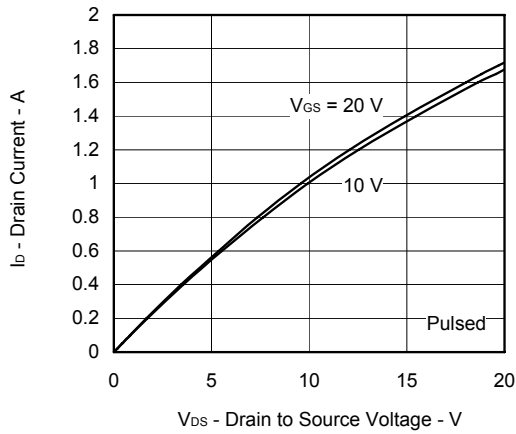
TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)



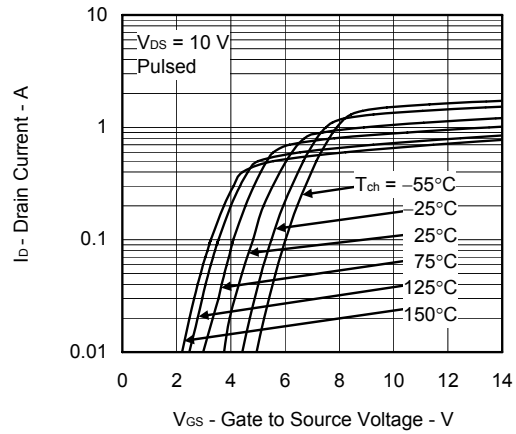
<R> TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



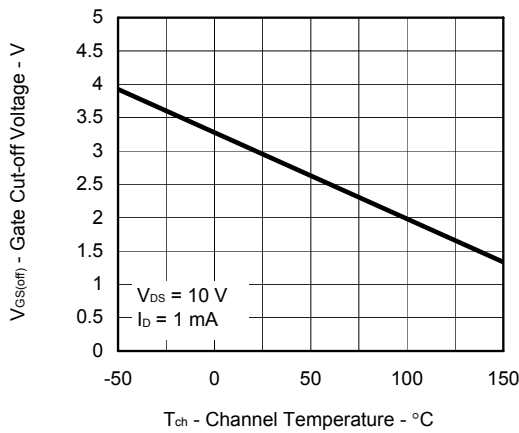
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



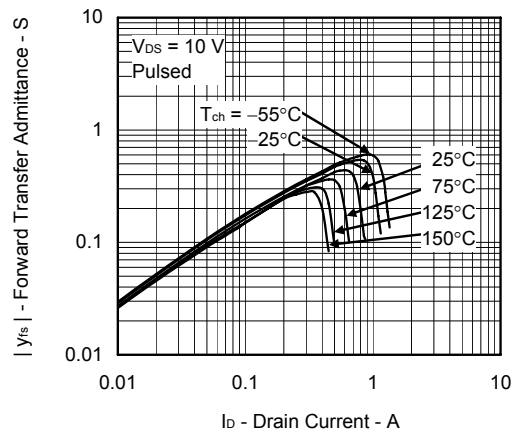
FORWARD TRANSFER CHARACTERISTICS



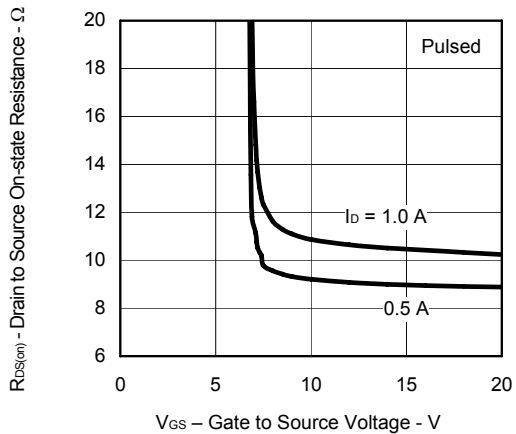
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



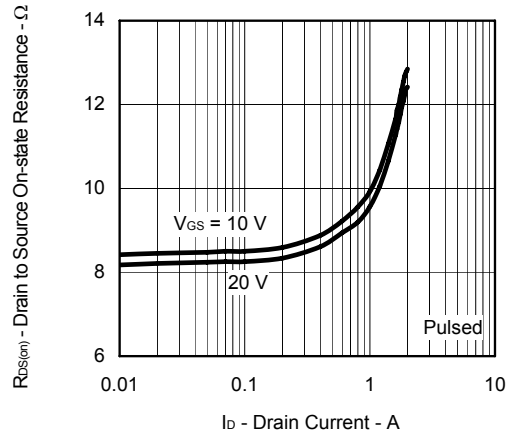
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

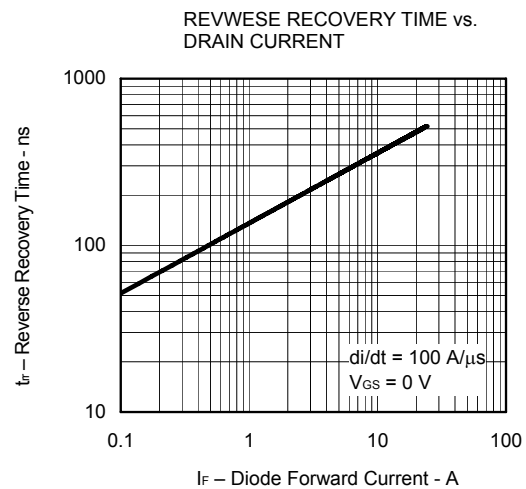
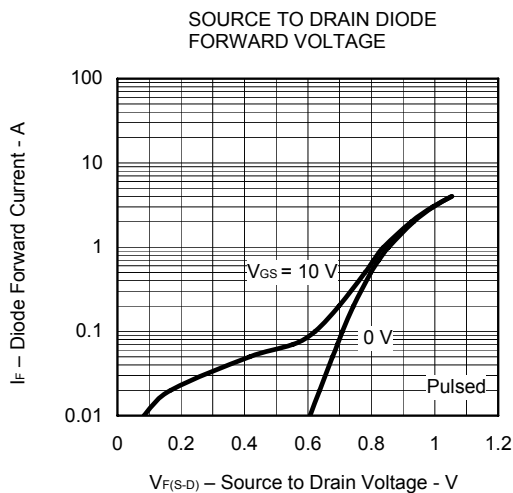
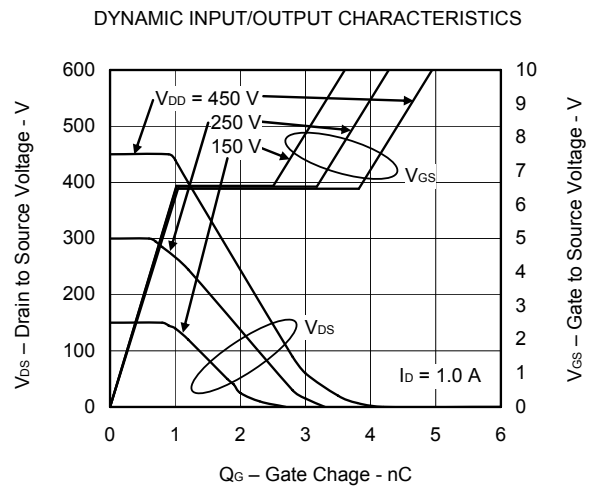
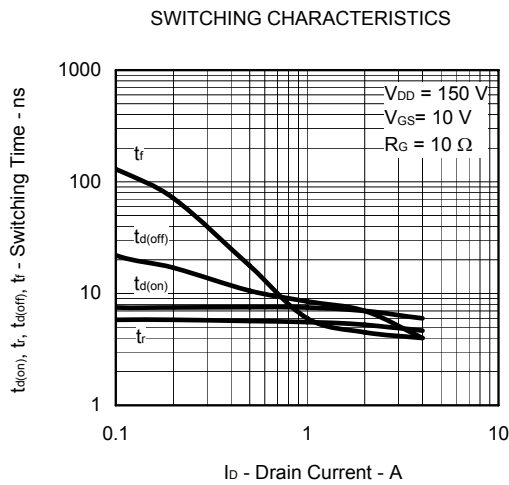
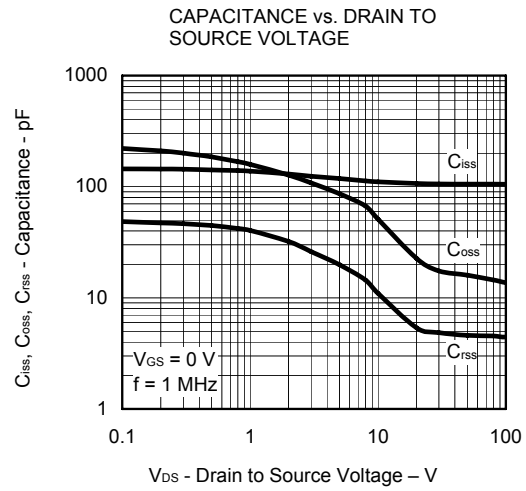
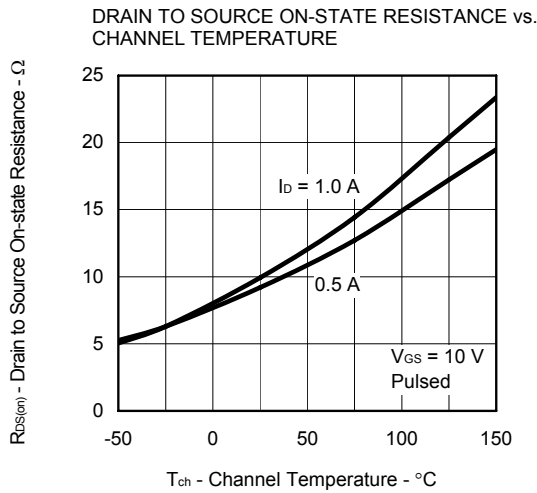


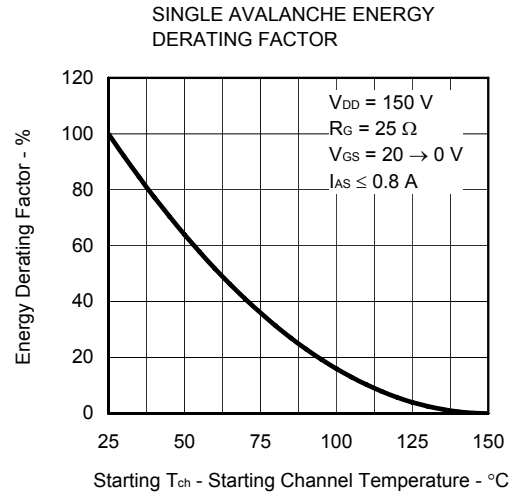
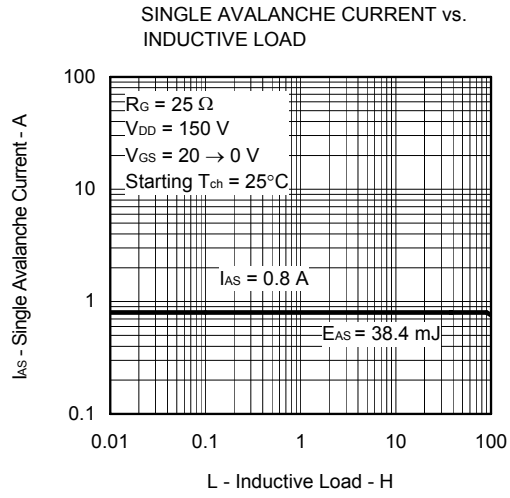
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT









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